

## ELECTRONIC TRANSPORT OF MOLECULAR JUNCTIONS CARBYNE AND TWO-DIMENSIONAL CARBON ALLOTROPES

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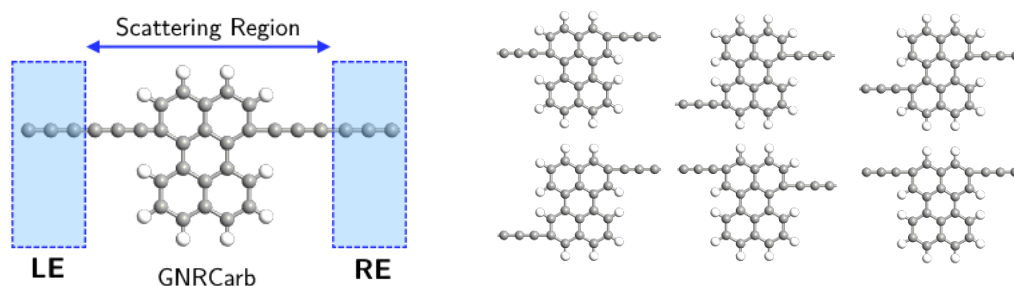
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### Abstract

In this work, we present an investigation, via the hybrid DFT-NEGF method [1], on the electronic transport of the molecular junction of carbon wires with a two-dimensional nanoribbon of carbon allotropes [2,3], from various junction configurations. The DFT calculations were performed with the generalized gradient approximation (GGA) and PBE functional, using computational package SIESTA 4.0 [4]. The influence of systematic variation in the bonds between carbyne and the nanoribbon was considered in the calculation. The systems were structurally stable, reaching a lower energy configuration, which was replicated in a device with a scattering region and electrodes. The devices exhibited metallic behavior, with a high probability of transmission. The I-V curve showed a tendency for gap opening with increasing voltage in the various structures, indicating a change in the transport regime. Thus, the systems proved to be very promising for the development of electronic nanodevices.



**Fig. 1.** (a) Molecular configuration of the junction device (GNRCarb). (b) Several configurations of the carbyne-graphene junction studied.

### References

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